



600V, SMPS IGBT

Manufacturer: ON Semiconductor, LLC

Package/Case: TO-247

Product Type: Thyristors

Lifecycle: LTB



Images are for reference only

Inquiry

General Description

The HGTG40N60A4 combines the best features of high input impedance of a MOSFET and the low on-state conduction loss of a bipolar transistor. This IGBT is ideal for many high voltage switching applications operating at high frequencies where low conduction losses are essential. This device has been optimized for fast switching applications, such as UPS and welder.

Key Features Application

C Other Industrial

J





Recommended For You

HGTG20N60B3D HGTG11N120CND HGTG20N60B3

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HGTP3N60A4 HGTG11N120CN HGTG12N60A4D

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HGTP7N60C3D

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HGTG27N120BN

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HGTG30N60A4D

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HGTG10N120BND

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HGTG30N60C3D

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HGTP7N60B3D

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HGTP10N120BN

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